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| APPLICATION NO.                   | FILING DATE               | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. |
|-----------------------------------|---------------------------|----------------------|---------------------|------------------|
| 10/806,588                        | 03/23/2004                | Yuko Ohgishi         | 09792909-5827       | 2229             |
| 26263 7                           | 590 01/10/2006            |                      | EXAMINER            |                  |
| SONNENSCHEIN NATH & ROSENTHAL LLP |                           |                      | SMITH, BRADLEY      |                  |
| P.O. BOX 0610<br>WACKER DR        | 080<br>IVE STATION, SEARS | STOWER               | ART UNIT            | PAPER NUMBER     |
| CHICAGO, II                       | •                         |                      | 2891                |                  |

DATE MAILED: 01/10/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

|  |  | ·  | ck   |
|--|--|--|------|
|  | Application No.  | Applicant(s)   |      |
|  | 10/806,588   | OHGISHI, YUKO  |      |
| Office Action Summary  | Examiner   | Art Unit   |      |
|  | Bradley K. Smith   | 2891   |      |
| The MAILING DATE of this communication of Period for Reply   | appears on the cover sheet w   | vith the correspondence address  |      |
| A SHORTENED STATUTORY PERIOD FOR REL WHICHEVER IS LONGER, FROM THE MAILING - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication If NO period for reply is specified above, the maximum statutory peri - Failure to reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the may be earned patent term adjustment. See 37 CFR 1.704(b). | B DATE OF THIS COMMUN<br>R 1.136(a). In no event, however, may a<br>riod will apply and will expire SIX (6) MC<br>atute, cause the application to become A | IICATION. a reply be timely filed  DNTHS from the mailing date of this communicatio ABANDONED (35 U.S.C. § 133). |      |
| Status   |  |  |      |
| 1) Responsive to communication(s) filed on 20  | <u> 0 December 2005</u> .  | - •  |      |
|  | This action is non-final.  |  |      |
| 3) Since this application is in condition for allow closed in accordance with the practice under   | wance except for formal ma   |  | is   |
| Disposition of Claims  |  |  |      |
| 4) ☐ Claim(s) 1-13 is/are pending in the application 4a) Of the above claim(s) 1-7 is/are withdraw 5) ☐ Claim(s) is/are allowed.  6) ☐ Claim(s) 8-13 is/are rejected.  7) ☐ Claim(s) is/are objected to.  8) ☐ Claim(s) are subject to restriction and   | wn from consideration.   | - •  |      |
| Application Papers   |  |  |      |
| 9) The specification is objected to by the Exam  |  | . <b>.</b>   |      |
| 10)⊠ The drawing(s) filed on <u>23 <i>March</i> 2004</u> is/are  |  |  |      |
| Applicant may not request that any objection to t  | <del>-</del> ,,  | • •  |      |
| Replacement drawing sheet(s) including the corr  | ·  | * , , ,  | (d). |
| Priority under 35 U.S.C. § 119   | EAGINION TOTAL CO.   | A Chica rision of roll   |      |
| 12) Acknowledgment is made of a claim for forei a) All b) Some * c) None of:  1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the p application from the International Bure * See the attached detailed Office action for a l   | ents have been received. ents have been received in a priority documents have been eau (PCT Rule 17.2(a)).   | Application No n received in this National Stage   |      |
|  |  |  |      |
| •  |  | •  |      |
| Attachment(s)  |  |  |      |
| I) ⊠ Notice of References Cited (PTO-892)<br>2) ☑ Notice of Draftsperson's Patent Drawing Review (PTO-948)   |  | Summary (PTO-413)<br>o(s)/Mail Date  |      |
| B) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0<br>Paper No(s)/Mail Date  |  | Informal Patent Application (PTO-152)  |      |

## **DETAILED ACTION**

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## Election/Restrictions

Applicant's election of group II in the reply filed on 12/20/05 is acknowledged. Because applicant did not distinctly and specifically point out the supposed errors in the restriction requirement, the election has been treated as an election without traverse (MPEP § 818.03(a)).

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 8-12 are rejected under 35 U.S.C. 102(e) as being anticipated by Ha et al. (2002/0072182). Ha disclose a semiconductor substrate and a plurality of electronic circuit elements formed at parts of the semiconductor substrate for each electrically independent region and including insulating films and electrodes formed on the insulating films, the insulating films differing in required electrical effective thickness for each electronic circuit element, and the electrodes having different concentrations of impurities for each circuit element according to the effective thickness (paragraphs 0006 and 0021-0026). With regards to claim 9, Ha disclose the transistors have different

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effective thicknesses. With regards to claim 10 and 11, Ha disclose the circuit elements being transistors and the electrode could act as capacitors and the oxide could act as a capacitive film. With regards to claim 12, Yoshiyama disclose the transistors having the same gate thicknesses.

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 8-11 and 13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yoshiyama et al. in view of Branak et al. Yoshiyama et al. disclose a semiconductor substrate (1) and a plurality of electronic circuit elements formed at parts of the semiconductor substrate for each electrically independent region and including insulating films (6, 4) and electrodes formed on the insulating films, the insulating films differing in required electrical effective thickness for each electronic circuit element (see figure 1). With regards to claim 10 and 11, Yoshiyama disclose the circuit elements being transistors and the electrode could act as capacitors and the oxide could act as a capacitive film. With regards to claim 13, Yoshiyama disclose the transistors having

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different gate thicknesses. However Yoshiyama et al. fails to disclose the electrodes having different concentrations of impurities, whereas Barnak et al. disclose that the doping to modify the polysilicon work function is well known in the art. Therefore it would have been obvious to one of ordinary skill in the art at the time the invention was made to combine the teachings of Yoshiyama and Barnak because it is well known that one can change the impurity doping in order to affect the work function (or electrical characteristics of the device).

### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Bradley K. Smith whose telephone number is 571-272-1884. The examiner can normally be reached on 10-6.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Bill Baumeister can be reached on 571-272-1722. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR.

Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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Bradley K Smith Primary Examiner Art Unit 2891

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